

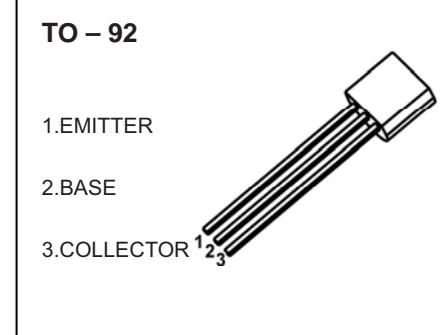
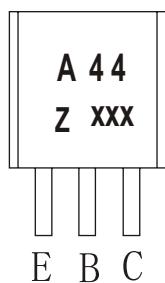


JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD.

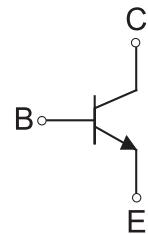
## TO-92 Plastic-Encapsulate Transistors

**MPSA44** TRANSISTOR (NPN)**FEATURES**

- High Breakdown Voltage

**MARKING**

A44=Device code  
Z=Rank of  $h_{FE}$   
XXX=Code  
GXX=Green molding compound device  
CXX=Normal molding compound device

**Equivalent Circuit****ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
MPSA44	TO-92	Bulk	1000pcs/Bag
MPSA44-TA	TO-92	Tape	2000pcs/Box

**MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	400	V
$V_{CEO}$	Collector-Emitter Voltage	400	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_c$	Collector Current -Continuous	0.3	A
$P_D$	Collector Power Dissipation	625	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	200	$^\circ\text{C}/\text{W}$
$T_J, T_{stg}$	Operation Junction and Storage Temperature Range	-55~+150	$^\circ\text{C}$

## ELECTRICAL CHARACTERISTICS

$T_a=25^\circ C$  unless otherwise specified

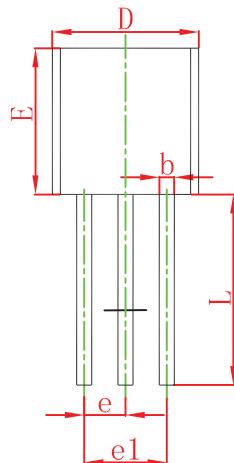
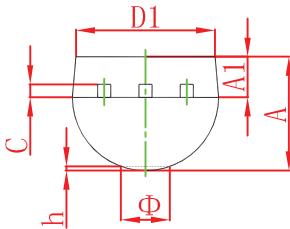
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=0.1mA, I_E=0$	400			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}^*$	$I_C=1mA, I_B=0$	400			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=0.1mA, I_C=0$	6			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=400V, I_E=0$			0.1	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=4V, I_C=0$			0.1	$\mu A$
DC current gain	$h_{FE(1)}^*$	$V_{CE}=10V, I_C=1mA$	40			
	$h_{FE(2)}^*$	$V_{CE}=10V, I_C=10mA$	100		200	
	$h_{FE(3)}^*$	$V_{CE}=10V, I_C=50mA$	45			
	$h_{FE(4)}^*$	$V_{CE}=10V, I_C=100mA$	40			
Collector-emitter saturation voltage	$V_{CE(sat)(1)}^*$	$I_C=1mA, I_B=0.1mA$			0.4	V
	$V_{CE(sat)(2)}^*$	$I_C=10mA, I_B=1mA$			0.5	
	$V_{CE(sat)(3)}^*$	$I_C=50mA, I_B=5mA$			0.75	
Base-emitter saturation voltage	$V_{BE(sat)}^*$	$I_C=10mA, I_B=1mA$			0.75	V
Collector output capacitance	$C_{ob}$	$V_{CB}=20V, I_E=0, f=1MHz$			7	pF
Emitter input capacitance	$C_{ib}$	$V_{EB}=0.5V, I_C=0, f=1MHz$			130	pF

\*Pulse test: pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2.0\%$ .

### CLASSIFICATION OF $h_{FE}(2)$

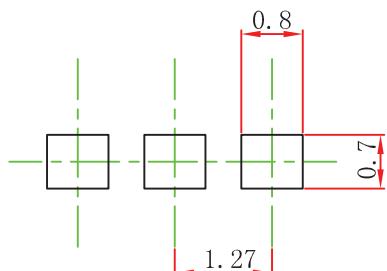
RANK	B
RANGE	100-200

## TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

## TO-92 Suggested Pad Layout



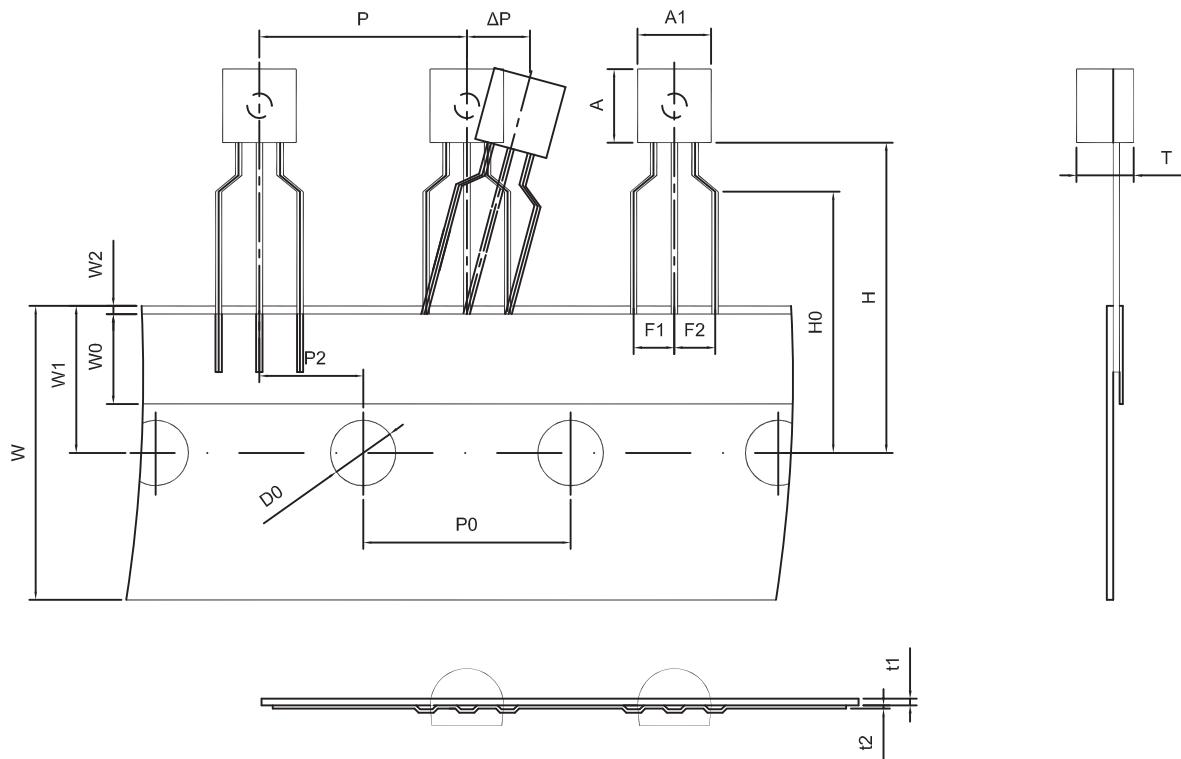
### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05$ mm.
3. The pad layout is for reference purposes only.

### NOTICE

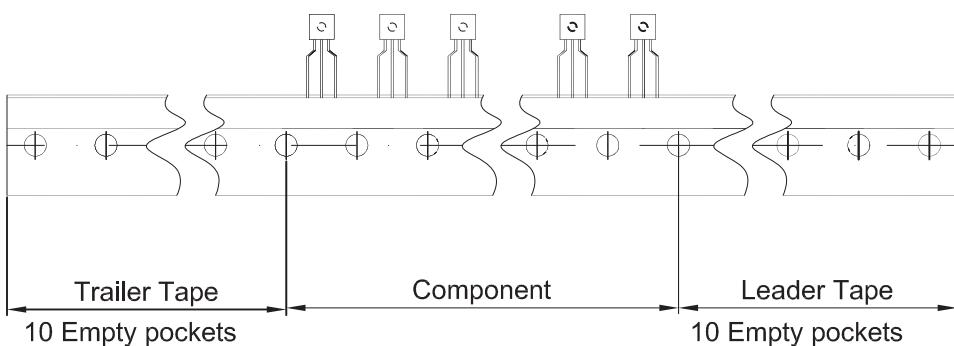
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## TO-92 Tape and Reel



Dimensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	$\Delta P$
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250